Code: 041404

B.Tech 4th Semester Exam., 2018

ANALOG ELECTRONICS

Time: 3 hours Full Marks: 70

Instructions:

- (i) The marks are indicated in the right-hand margin.
- (ii) There are **NINE** questions in this paper.
- (iii) Attempt FIVE questions in all.
- (iv) Question No. 1 is compulsory.
- 1. Choose the correct answer from the following (any seven): 2×7=14
 - (a) When there is no base current in a transistor switch, the output voltage from the transistor is
 - (i) low
 - (ii) high
 - (iii) unchanged
 - (iv) unknown

- (e) Why do the internal capacitances of transistor at low frequencies treated as open circuits by completely neglecting their effects in analysis?
 - Due to high reactance
 - (ii) Due to low reactance
 - (iii) Due to moderate reactance
 - (iv) None of the above
 - (f) Which among the below assertions is not a salient feature/property of CE amplifier?
 - (i) High voltage gain
 - (ii) High current gain
 - انتزل High input resistance
 - (iv) High output resistance
 - (g) In a power amplifier, the collector current flows for 270° of the input cycle. The operation is
 - (i) class A
 - (ii) class B
 - (iii) class AB
 - class C استال

- (h) Which capacitor is used to block DC portion by allowing to pass only AC portion of the amplified signal to load?
 - (i) Input coupling capacitor

Bypass capacitor

(iii) Output coupling capacitor

-fiv) All of the above

- (i) When the circuit is switched on, the loop gain of an Wien bridge oscillator is
 - (i) 1
 - (ii) more than 1
 - (iii) less than 1
 - (iv) about 0.5
- (j) If Q of an L-C circuit increases, then bandwidth
 - (i) increases
 - (ii) decreases
 - (iii) remains the same
 - (iv) Insufficient data
- (a) Explain the frequency distortion in amplifier and list the various causes for distortion.

- (b) If the emitter resistance increases, the collector voltage
 - (i) decreases
 - (ii) stays the same
 - (iii) increases
 - (iv) breaks down the transistor
- (c) Consider 49 cascaded amplifiers having individual rise time as 2 n sec, 3 n sec, ... 50 n sec. The input waveform rise time is 1 n sec. Then the output signal rise time is given by (assume output signal rise time is measured within 10 percent range of the final output signal)
 - (i) 39-28 µ sec
 - (ii) 2·28 μ sec
 - (iii) 0.228 µ sec
 - (iv) 39.28 µ sec
- (d) Which capacitance(s) in hybrid π model represent(s) the storage of excess minority carriers at the base emitter junction?
 - (i) Diffusion capacitance
 - (ii) Transition capacitance
 - (iii) Both (i) and (ii)
 - (iv) None of the above

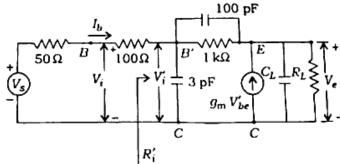
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(b) Draw the approximate small-signal equivalent circuit at low frequency for common-collector amplifier with load resistance R_L. Compute the input resistance in terms of h parameters.

7+7=14

- (a) Draw and explain the working of lowfrequency small-signal equivalent circuit of common base BJT.
 - (b) Compute the input impedance R_i' using the equivalent circuit diagram given in figure below at frequency f = 30 MHz, where $g_m = 50$ mA/V, $R_L = 2$ k Ω and $C_L = 20$ pF.



6+8=14

4, (a)

Draw and explain the working of Bootstrapped Darlington circuit.

(b) Explain the f_{β} and f_{T} , which are bandwidths of the circuit and short-circuit current-gain bandwidth products respectively.

- 5. (a) The input to a low-pass amplifier is a pulse of width t_p. Sketch the output waveform and explain the intermediate steps involved to achieve the output.
 - (b) What must be the relationship between t_p and high 3-dB frequency f_H in order to amplify the pulse without excessive distortion? 10+4=14
- 6. (a) Compute overall upper 3-dB frequency for four interacting stages amplifier having individual stage upper 3-dB frequency, $f_1 = 4 \text{ MHz}$, $f_2 = 4.2 \text{ MHz}$, $f_3 = 4.1 \text{ MHz}$ and $f_4 = 3.9 \text{ MHz}$.
 - (b) Define tilt. How is the tilt related to the low 3-dB frequency f_L ? 8+6=14
- 7. (a) Explain thermal and shot noises associated to the amplifier and briefly discuss the thermal-resistance noise voltage and mean-square shot-noise current in the context of thermal and shot noises respectively.
 - (b) Compute the expression for current gain using small-signal equivalent circuit at high frequency for commonsource FET amplifier with load resistance R_L. 7+7=14

- 8./(a) Explain the working of phase-shift oscillator.
 - (b) Derive expression for the oscillation frequency of a Colpitts oscillator and compute its value for given L = 10 mH, $C_1 = 24$ nF and $C_2 = 240$ nF. 7+7=1
- 9. (a) Explain the working of class-B pushpull amplifier and compute the maximum conversion efficiency.
 - (b) Compute the bandwidth for singletuned BJT amplifier using one parallel tuned circuit as load. 7+7=1